

N-Ch MOSFET

General Description

The WSR7N65F is the highest performance trench N-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSR7N65F meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge •
- Excellent Cdv/dt effect decline •

Absolute Maximum Ratings

Green Device Available

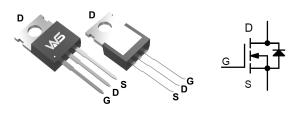
Product Summery

BV _{DSS}	R _{DSON}	I _D
650V	1.3Ω	7A

Applications

- AC/DC Power Conversion in Switched Mode Power Supplies (SMPS).
- Uninterruptible Power Supply(UPS)
- Adapter.

TO-220F Pin Configuration



Symbol **Parameter** Rating Units 650 v **Drain-Source Voltage** V_{DS} V Gate-Source Voltage ± 30 V_{GS} Continuous Drain Current, V_{GS} @ 10V^{1.5} 7 А I_D@T_C=25℃ Continuous Drain Current, V_{GS} @ 10V^{1.5} 4 I_D@T_C=100℃ А Pulsed Drain Current^{1.2.5} 28 А I_{DM} Single Pulse Avalanche Energy¹ EAS 171 mJ PD W Total Power Dissipation^{1,5} 48 Storage Temperature Range °C T_{STG} -55 to 150 °C ΤJ **Operating Junction Temperature Range** -55 to 150

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit	
R _{ejA}	Thermal Resistance Junction-ambient ¹		62.5	°C/W	
R _{θJC}	Thermal Resistance Junction-Case ¹		2.7	°C/W	



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Electrical Characteristics (T_J=25¹C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	650			V
$\triangle BV_{DSS} / \triangle T_J$	BVDSS Temperature Coefficient	Reference to 25° C , I _D =250uA		0.6		V/℃
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =3.5A		1.0	1.3	Ω
V _{GS(th)}	Gate Threshold Voltage	—V _{GS} =V _{DS} , I _D =250uA	2.0	3.0	4.0	V
$ riangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient			-4.57		mV/℃
I _{DSS}	Drain-Source Leakage Current	V_{DS} =650V , V_{GS} =0V , T_J =25 $^\circ\!\mathbb{C}$			1	uA
		V _{DS} =520V , V _{GS} =0V , T _J =55℃			10	
I _{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm30V$, $V_{DS}=0V$			±100	nA
gfs	Forward Transconductance	V _{DS} =40V , I _D =3.5A		6		S
Qg	Total Gate Charge (10V)	V _{DS} =520V , V _{GS} =10V , I _D =7A		16		nC
Q _{gs}	Gate-Source Charge			4		
Q _{gd}	Gate-Drain Charge			3.6		
T _{d(on)}	Turn-On Delay Time			26		
Tr	Rise Time	V _{DD} =300V , V _{GS} =10V ,	17			
T _{d(off)}	Turn-Off Delay Time	R _G =25Ω, I _D =10A		57		ns
T _f	Fall Time			23		
C _{iss}	Input Capacitance	V _{DS} =25V , V _{GS} =0V , f=1MHz		930		
Coss	Output Capacitance			100		pF
C _{rss}	Reverse Transfer Capacitance			4.5		

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current ^{1,2,5}				7	А
I _{SM}	Pulsed Source Current ^{1,2}	$V_G = V_D = 0V$, Force Current			28	А
V _{SD}	Diode Forward Voltage ¹	V _{GS} =0V , I _S =7A , T _J =25℃			1.4	V
t _{rr}	Reverse Recovery Time			487		nS
Qrr	Reverse Recovery Charge	l₣=7A , dl/dt=40A/µs , Tյ=25℃		2289		nC

Notes:

- Note 1 : limited by maximum junction temperature.
- Note 2 : Bond wire current limit.
- Note 3 : V_{DS} =520V, I_{D} =7A.
- Note 4 : $I_D=0.5A$, $V_{DD}=50V$, $T_j=25^{\circ}C$.
- Note 5 : Repetitive Rating : Pulse width limited by maximum junction temperature.



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Typical Characteristics

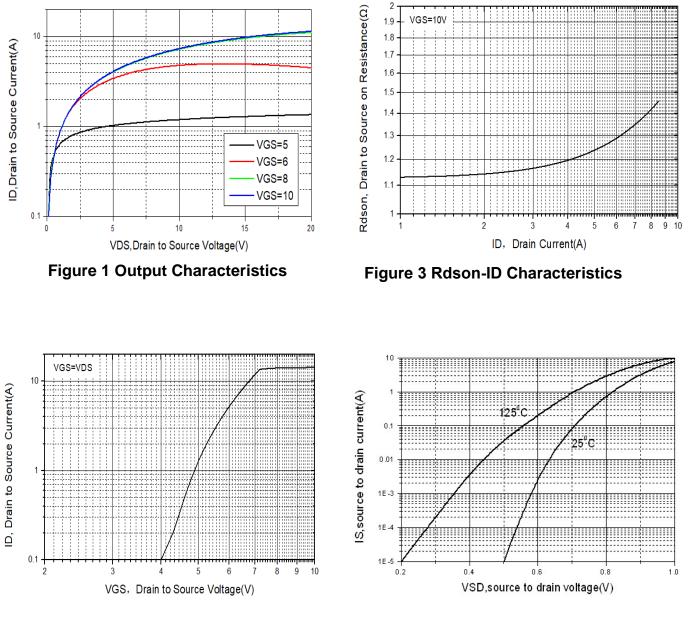


Figure 2 Transfer Characteristics

Figure 4 Body diode Characteristics



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Typical Characteristics

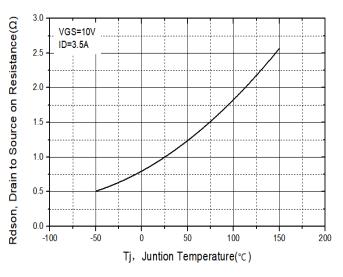


Figure 5 Rdson- Tj Relation

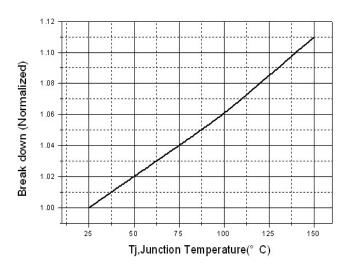


Figure 6 BVDSS vs Junction Temperature

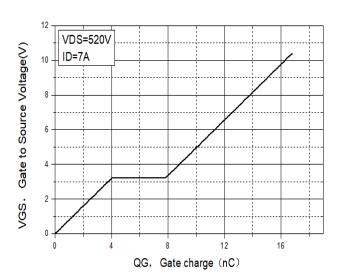
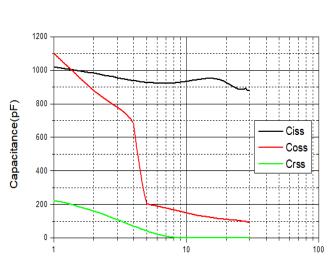


Figure 8 VGS vs QG Characteristics



VDS, Drain to Source Voltage(V)

Figure 7 Capacitance vs Vds



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Typical Characteristics

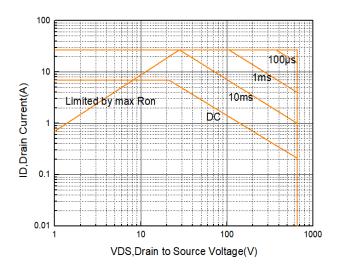


Figure 9 Safe Operation Area

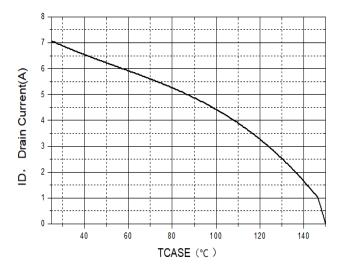


Figure 10 Maximum current attenuation

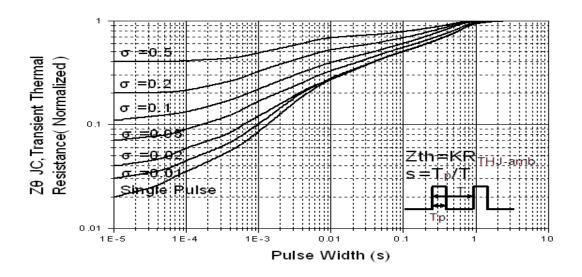


Figure 11 Normalized Maximum Transient Thermal Impedance



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